

TOSHIBA PHOTOCOUPLER PHOTO RELAY

TLP597G

CORDLESS TELEPHONE

PBX

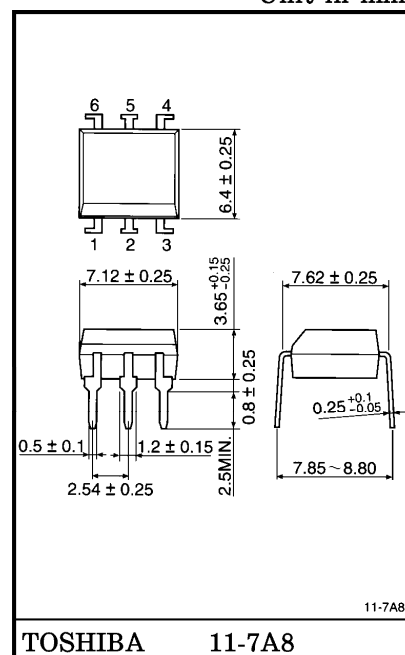
MODEM

The TOSHIBA TLP597G consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a six lead plastic DIP package (DIP6).

The TLP597G is a bi-directional switch which can replace mechanical relay in many applications.

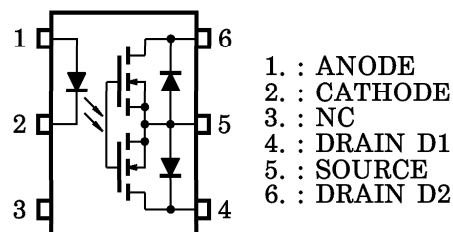
- Peak Off-State Voltage : 350 V (MIN.)
- Trigger LED Current : 3 mA (MAX.)
- On-State Current : 120 mA (MAX.) (A Connection)
- On-State Resistance : 35 Ω (MAX.) (A Connection)
- Isolation Voltage : 2500 V_{rms} (MIN.)
- Isolation Thickness : 0.4 mm (MIN.)
- UL Recognized : UL1577, File No. E67349
- BSI Approved
 - : BS EN60065 : 1994, Certificate No. 8275
 - BS EN60950 : 1992, Certificate No. 8276
- Option (D4) type
 - : TUV Approved : DIN VDE0884 / 06.92,
 - Certificate No. R9850585

Unit in mm

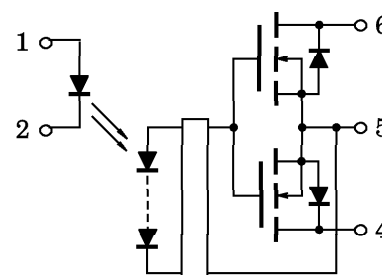


Weight : 0.4 g

PIN CONFIGURATION (TOP VIEW)



SCHEMATIC



980910EBC2

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- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
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MAXIMUM RATINGS (Ta = 25°C)

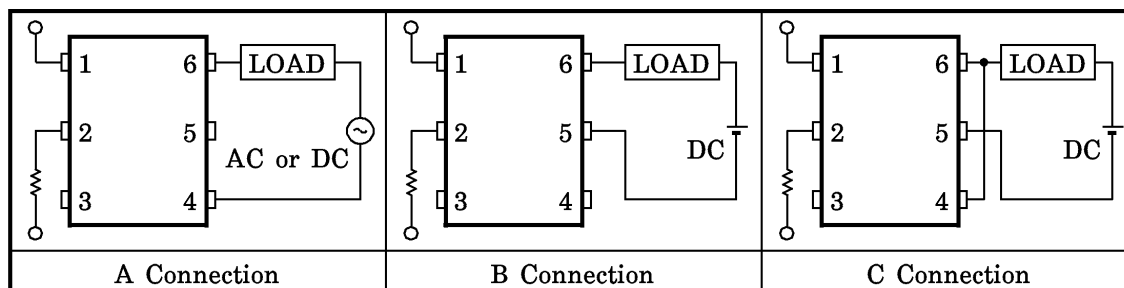
CHARACTERISTIC			SYMBOL	RATING	UNIT
LED	Forward Current		I _F	50	mA
	Forward Current Derating (Ta ≥ 25°C)		ΔI _F / °C	−0.5	mA / °C
	Peak Forward Current (100 μs pulse, 100 pps)		I _{FP}	1	A
	Reverse Voltage		V _R	5	V
	Junction Temperature		T _j	125	°C
DETECTOR	Off-State Output Terminal Voltage		V _{OFF}	350	V
	On-State RMS Current	A Connection	I _{ON}	120	mA
		B Connection		120	
		C Connection		160	
	On-State Current Derating (Ta ≥ 25°C)	A Connection	ΔI _{ON} / °C	−1.2	mA / °C
		B Connection		−1.2	
		C Connection		−1.6	
	Junction Temperature		T _j	125	°C
Storage Temperature Range		T _{stg}	−55~125	°C	
Operating Temperature Range		T _{opr}	−40~85	°C	
Lead Soldering Temperature (10 s)		T _{sol}	260	°C	
Isolation Voltage (AC, 1min., R.H. ≤ 60%) (Note 1)		BV _S	2500	V _{rms}	

(Note 1) : Device considered a two-terminal device : pins 1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{DD}	—	—	280	V
Forward Current	I_F	5	7.5	25	mA
On-State Current	I_{ON}	—	—	120	mA
Operating Temperature	T_{opr}	-20	—	65	°C

CIRCUIT CONNECTIONS



INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Off-State Current	I_{OFF}	$V_{OFF} = 350 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	40	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current		I_{FT}	$I_{ON} = 120 \text{ mA}$	—	1	3	mA
On-State Resistance	A Connection	R_{ON}	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	22	35	Ω
			$I_{ON} = 20 \sim 120 \text{ mA}, I_F = 5 \text{ mA}$	—	26	40	Ω
	B Connection		$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	13	20	Ω
	C Connection		$I_{ON} = 160 \text{ mA}, I_F = 5 \text{ mA}$	—	7	10	Ω

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500 \text{ V}, R.H. \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	2500	—	—	V_{rms}
		AC, 1 second, in oil	—	5000	—	
		DC, 1 minute, in oil	—	5000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t_{ON}	$R_L = 200 \Omega$ (Note 2)	—	0.3	1	ms
Turn-off Time	t_{OFF}	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	—	0.1	1	

(Note 2) : SWITCHING TIME TEST CIRCUIT

